







SN74LV373A-Q1

SCLS586D - JUNE 2004 - REVISED MARCH 2023

# SN74LV373A-Q1 Octal Transparent D-Type Latch With 3-State Outputs

#### 1 Features

- Qualified for automotive applications
- V<sub>CC</sub> operation of 2 V to 5.5 V
- Maximum tpd of 8.5 ns at 5 V
- Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot) > 2.3 V at  $V_{CC} = 3.3 \text{ V}, \text{ TA} = 25^{\circ}\text{C}$
- Supports mixed-mode voltage operation on all
- I<sub>off</sub> supports partial-power-down mode operation
- Latch-up performance exceeds 250 mA per JESD

# 2 Applications

- Synchronize digital signals to clock
- Use fewer inputs to monitor signals
- Convert a switch to a toggle

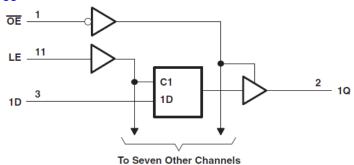
## 3 Description

The SN74LV373A-Q1 device is an octal transparent D-type latch designed for 2 V to 5.5 V V<sub>CC</sub> operation. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

## Package Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LV373A-Q1	PW (TSSOP, 20)	6.50 mm × 4.40 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

## Changes from Revision C (October 2007) to Revision D (March 2023)

Page

- Updated thermal values for PW package from RθJA = 83 to 128.2, all values in °C/W .......5



# **5 Pin Configuration and Functions**

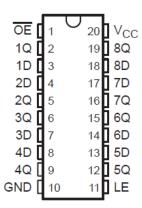


Figure 5-1. SN74LV373A-Q1 TSSOP -PW Package (Top View)

Table 5-1. Pin Function

F	PIN	TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
ŌĒ	1	Input	Output enable, active low
1Q	2	Output	Output for channel 1
1D	3	Input	Input for channel 1
2D	4	Input	Input for channel 2
2Q	5	Output	Output for channel 2
3Q	6	Output	Output for channel 3
3D	7	Input	Input for channel 3
4D	8	Input	Input for channel 4
4Q	9	Output	Output for channel 4
GND	10	_	Ground
LE	11	Input	Latch enable
5Q	12	Output	Output for channel 5
5D	13	Input	Input for channel 5
6D	14	Input	Input for channel 6
6Q	15	Output	Output for channel 6
7Q	16	Output	Output for channel 7
7D	17	Input	Input for channel 7
8D	18	Input	Input for channel 8
8Q	19	Output	Output for channel 8
V <sub>CC</sub>	20	_	Positive supply
Thermal Pad <sub>1</sub>		_	The thermal pad can be connect to GND or left floating. Do not connect to any other signal or supply.



## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

Over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
VI	Input voltage <sup>(2)</sup>				V
Vo	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>		-0.5	7	V
Vo	Output voltage (2) (3)		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA
	Continuous current through V <sub>CC</sub> or GND		±70	mA	
$\theta_{JA}$	Package thermal impedance			83	°C/W
T <sub>stg</sub>			-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

## 6.2 ESD Ratings

			VALUE	UNIT
	(ESD) Electrostatic discharge	Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2 <sup>(1)</sup>		
V <sub>(ESD)</sub>		Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±2000	V

(1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 5.5 V maximum.



# **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT		
V <sub>CC</sub>	Supply voltage		2	5.5	V		
		V <sub>CC</sub> = 2 V	1.5				
\	Lligh level input veltage	V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V		
V <sub>IH</sub>	High-level input voltage	VCC = 3 V to 3.6 V	V <sub>CC</sub> × 0.7		V		
		VCC = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7				
		V <sub>CC</sub> = 2 V		0.5			
\ /	Low lovel input veltage	V <sub>CC</sub> = 2.3 V to 2.7 V	V	V <sub>CC</sub> × 0.3			
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	V	′ <sub>CC</sub> × 0.3	$\rightarrow$ $\vee$		
		V <sub>CC</sub> = 4.5 V to 5.5 V	V	′ <sub>CC</sub> × 0.3			
VI	Input voltage		0	5.5	V		
\/	Output voltage	High or low state	0	V <sub>CC</sub>	V		
Vo		3-state	0	5.5	V		
	High-level output current	V <sub>CC</sub> = 2 V		-50	μA		
		V <sub>CC</sub> = 2.3 V to 2.7 V		-2			
I <sub>OH</sub>		V <sub>CC</sub> = 3 V to 3.6 V		-8	mA		
		V <sub>CC</sub> = 4.5 V to 5.5 V		-16			
		V <sub>CC</sub> = 2 V		50	μA		
	Low-level output current	V <sub>CC</sub> = 2.3 V to 2.7 V		2			
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 3 V to 3.6 V		8	mA		
		V <sub>CC</sub> = 4.5 V to 5.5 V		16			
		V <sub>CC</sub> = 2.3 V to 2.7 V		200			
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 3 V to 3.6 V		100	ns/V		
		V <sub>CC</sub> = 4.5 V to 5.5 V		20			
T <sub>A</sub>	Operating free-air temperature		-40	85	°C		

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See *Implications of Slow or Floating CMOS Inputs*.

## **6.4 Thermal Information**

		SN74LV373A-Q1	
	THERMAL METRIC(1)	PW (TSSOP)	UNIT
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	128.2	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.



### 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted).

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP MAX	UNIT
	I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> - 0.1		
V	I <sub>OH</sub> = -2 mA	2.3 V	2		
V <sub>OH</sub>	I <sub>OH</sub> = -8 mA	3 V	2.48		]
	I <sub>OH</sub> = -16 mA	4.5 V	3.8		
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V		0.1	
V	I <sub>OL</sub> = 2 mA	2.3 V		0.4	
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	3 V		0.44	]
	I <sub>OL</sub> = 16 mA	4.5 V		0.55	
II	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V		±1	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V		±5	μA
I <sub>cc</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		20	μA
I <sub>off</sub>	$V_{I}$ or $V_{O} = 0$ to 5.5 V	0 V		5	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		2.9	pF

## 6.6 Timing Requirements, 2.5 V ± 0.2 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

	MIN	MAX	UNIT		
t <sub>w</sub>	Pulse duration, LE high		6.5		ns
t <sub>su</sub>	Setup time, data before LE↓	High or low	5		ns
t <sub>h</sub>	Hold time, data after LE↓	High or low	1.5		ns

# 6.7 Timing Requirements, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

			MIN N	ΙΑХ	UNIT
t <sub>w</sub>	Pulse duration, LE high		5		ns
t <sub>su</sub>	Setup time, data before LE↓	High or low	4		ns
t <sub>h</sub>	Hold time, data after LE↓	High or low	1		ns

# 6.8 Timing Requirements, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

			MIN MAX	UNIT
t <sub>w</sub>	Pulse duration, LE high			ns
t <sub>su</sub>	Setup time, data before LE↓	High or low	4	ns
t <sub>h</sub>	Hold time, data after LE↓	High or low	1	ns

## **6.9 Switching Characteristics**

over operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM	то	LOAD	2.5 V :	± 0.2 V	3.3 V ± 0	).3 V	5 V ±	0.5 V	UNIT
PARAIVIETER	(INPUT) (OUTPUT) CAI	CAPACITANCE	MIN	MAX	MIN	MAX	MIN	MAX	ONT	
+	D	Q		1	17	1	13.5	1	8.5	no
<sup>L</sup> pd	LE	Q	C = 15 pE	1	19	1	13	1	8.5	ns
t <sub>en</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF	1	19	1	13.5	1	9.5	ns
t <sub>dis</sub>	ŌĒ	Q		1	15	1	12	1	8.5	ns

over operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM TO LOAD 2.5 V ± 0.2 V		3.3 V ± 0.3 V		5 V ± 0.5 V		UNIT			
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	MAX	MIN	MAX	MIN	MAX	ONII
	D	Q	- C <sub>L</sub> = 50 pF -	1	21	1	17	1	10.5	ns
ι <sub>pd</sub>	LE	Q		1	22	1	16.5	1	10.5	
t <sub>en</sub>	ŌĒ	Q		1	22	1	17	1	11.5	ns
t <sub>dis</sub>	ŌĒ	Q		1	19	1	15	1	10.5	ns
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF		2		1.5		1	ns

## **6.10 Noise Characteristics**

 $V_{CC} = 3.3 \text{ V}, C_1 = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ 

	PARAMETER <sup>(1)</sup>	SN74	SN74LV373A-Q1				
	FARAWE I ER	MIN	TYP	MAX	UNIT		
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>	,	0.6	0.8	V		
$V_{OL(V)}$	Quiet output, minimum dynamic V <sub>OL</sub>		-0.6	-0.8	V		
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		2.9		V		
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			V		
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.99	V		

<sup>(1)</sup> Characteristics for surface-mount packages only.

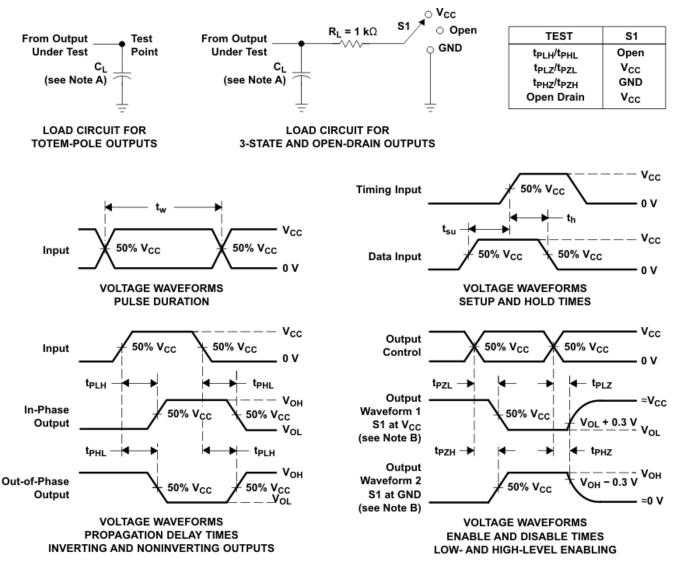
## **6.11 Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
C .	Power dissipation capacitance (outputs enabled)	C <sub>1</sub> = 50 pF, f = 10 MHz	3.3 V	17.4	pF
Opd	Power dissipation capacitance (outputs enabled)	O <sub>L</sub> = 30 μr, τ = 10 Μπ2	5 V	19.5	



### 7 Parameter Measurement Information



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq$  3 ns, and  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PHL</sub> and t<sub>PLH</sub> are the same as t<sub>pd</sub>.
- H. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage Waveforms



## **8 Detailed Description**

## 8.1 Overview

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

 $\overline{\text{OE}}$  does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  shall be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

## 8.2 Functional Block Diagram

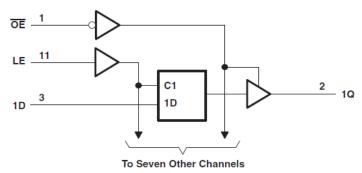


Figure 8-1. Logic Diagram (Positive Logic)



### 8.3 Device Functional Modes

**Table 8-1. Function Table** 

	OUTPUT <sup>(2)</sup>		
CLR	CLK	D	Q
L	Х	Х	L
Н	L, H, ↓	Х	$Q_0$
Н	1	L	L
Н	1	Н	Н

- (1) L = input low, H = input high,  $\uparrow$  = input transitioning from low to high, ↓ = input transitioning from high to low, X = do not care L = output low, H = output high, Q<sub>0</sub> = previous state

## 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Absolute Maximum Ratings* section. Each  $V_{CC}$  terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1- $\mu$ F capacitor; if there are multiple  $V_{CC}$  terminals, then TI recommends a 0.01- $\mu$ F or 0.022- $\mu$ F capacitor for each power terminal. Multiple bypass capacitors can be paralleled to reject different frequencies of noise. Frequencies of 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor must be installed as close as possible to the power terminal for best results.

## 9.2 Layout

### 9.2.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

### 9.2.1.1 Layout Example

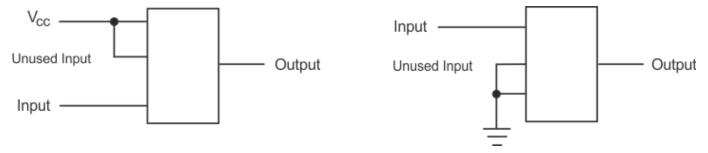


Figure 9-1. Layout Diagram



## 10 Device and Documentation Support

## 10.1 Documentation Support

#### 10.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 10-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV373A-Q1	Click here	Click here	Click here	Click here	Click here

## 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates—including silicon errata—go to the product folder for your device on ti.com. In the upper right-hand corner, click the *Alert me* button. This registers you to receive a weekly digest of product information that has changed (if any). For change details, check the revision history of any revised document.

## 10.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
SN74LV373AIPWRG4Q1	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV373AI
SN74LV373AIPWRG4Q1.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV373AI
SN74LV373AIPWRQ1	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-3-260C-168 HR	-40 to 85	LV373AI
SN74LV373AIPWRQ1.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	LV373AI
SN74LV373AIPWRQ1.B	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	-	NIPDAU	Level-3-260C-168 HR	-40 to 85	LV373AI

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE OPTION ADDENDUM**

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#### OTHER QUALIFIED VERSIONS OF SN74LV373A-Q1:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

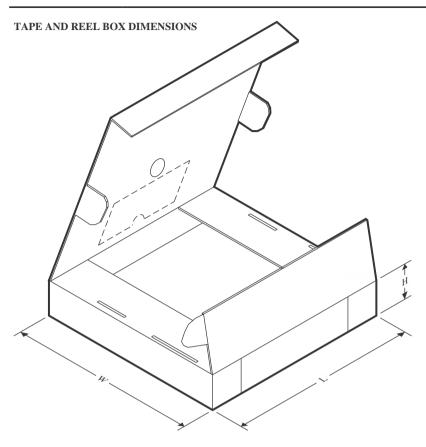
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV373AIPWRG4Q1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV373AIPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV373AIPWRG4Q1	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74LV373AIPWRQ1	TSSOP	PW	20	2000	353.0	353.0	32.0



SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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